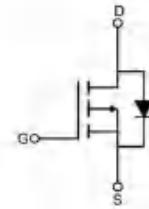


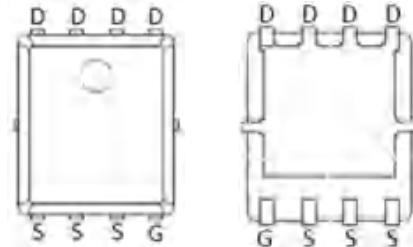
## Feature

- -60V,-30A
- $R_{DS(ON)} < 30m\Omega @ V_{GS} = -10V$  TYP:23 m $\Omega$
- $R_{DS(ON)} < 38m\Omega @ V_{GS} = -4.5V$  TYP:27 m $\Omega$
- Advanced Trench Technology
- Lead free product is acquired
- Excellent  $R_{DS(ON)}$  and Low Gate Charge



## Application

- PWM applications
- Load Switch
- Power management



PDFN5X6-8L

## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
30P06G	AP30P06K	PDFN5*6-8L	13 inch	-	5000

## ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current ( $T_a = 25^\circ C$ )	$I_D$	-30	A
Continuous Drain Current ( $T_a = 100^\circ C$ )	$I_D$	-20	A
Pulsed Drain Current <sup>(1)</sup>	$I_{DM}$	-120	A
Singel Pulsed Avalanche Energy <sup>(2)</sup>	$E_{AS}$	90	mJ
Power Dissipation	$P_D$	35	W
Thermal Resistance from Junction to Case	$R_{eJC}$	3.8	$^\circ C/W$
Junction Temperature	$T_J$	150	$^\circ C$
Storage Temperature	$T_{STG}$	-55~+150	$^\circ C$

**MOSFET ELECTRICAL CHARACTERISTICS( $T_a=25^\circ C$  unless otherwise noted)**

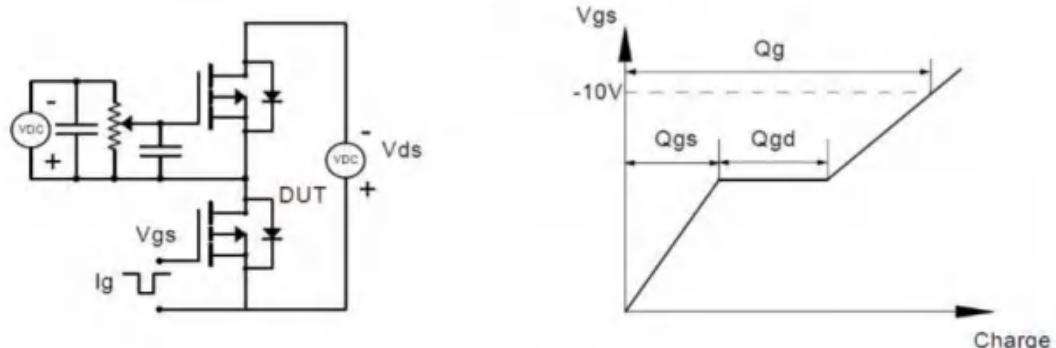
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-60	-	-	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = -60V, V_{GS} = 0V$	-	-	1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	$\pm 100$	nA
Gate threshold voltage <sup>(3)</sup>	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.7	-2.5	V
Drain-source on-resistance <sup>(3)</sup>	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -15A$	-	23	30	$m\Omega$
		$V_{GS} = -4.5V, I_D = -10A$	-	27	38	
<b>Dynamic characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = -25V, V_{GS} = 0V, f = 1MHz$	-	2400	-	$pF$
Output Capacitance	$C_{oss}$		-	251	-	
Reverse Transfer Capacitance	$C_{rss}$		-	196	-	
<b>Switching characteristics</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -30V, I_D = -30A, R_L = 3\Omega$ $V_{GS} = -10V, R_G = 3\Omega$	-	15	-	$ns$
Turn-on rise time	$t_r$		-	120	-	
Turn-off delay time	$t_{d(off)}$		-	245	-	
Turn-off fall time	$t_f$		-	199	-	
Total Gate Charge	$Q_g$	$V_{DS} = -30V, I_D = -15A,$ $V_{GS} = -10V$	-	49	-	$nC$
Gate-Source Charge	$Q_{gs}$		-	8	-	
Gate-Drain Charge	$Q_{gd}$		-	12	-	
<b>Source-Drain Diode characteristics</b>						
Diode Forward voltage <sup>(2)</sup>	$V_{DS}$	$V_{GS} = 0V, I_S = -10A$	-	-	-1.2	V
Diode Forward current <sup>(3)</sup>	$I_S$		-	-	-30	A

**Notes:**

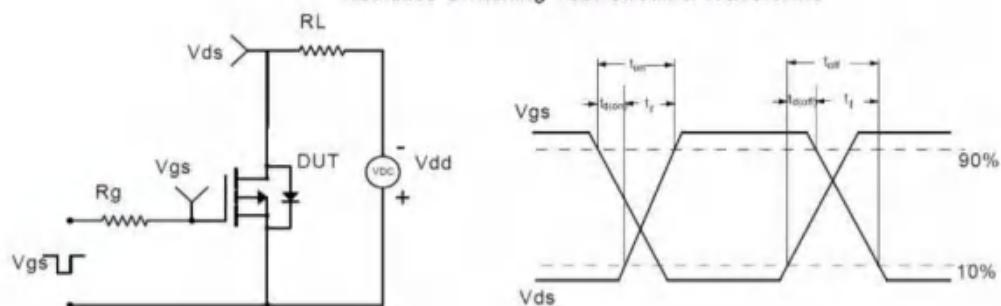
1. Repetitive Rating: pulse width limited by maximum junction temperature
2. EAS Condition: $T_J = 25^\circ C, V_{DD} = -30V, R_G = 20\Omega, L = 0.5mH$
3. Pulse Test: pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$
4. Surface Mounted on FR4 Board,  $t \leq 10$  sec

## Test Circuit

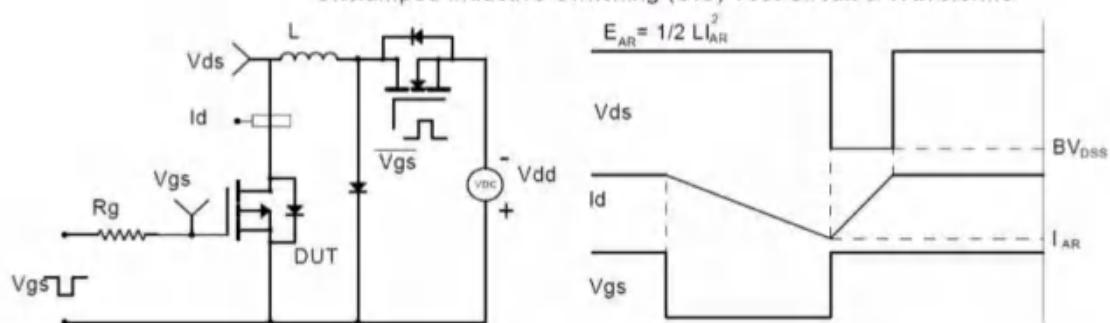
Gate Charge Test Circuit & Waveform



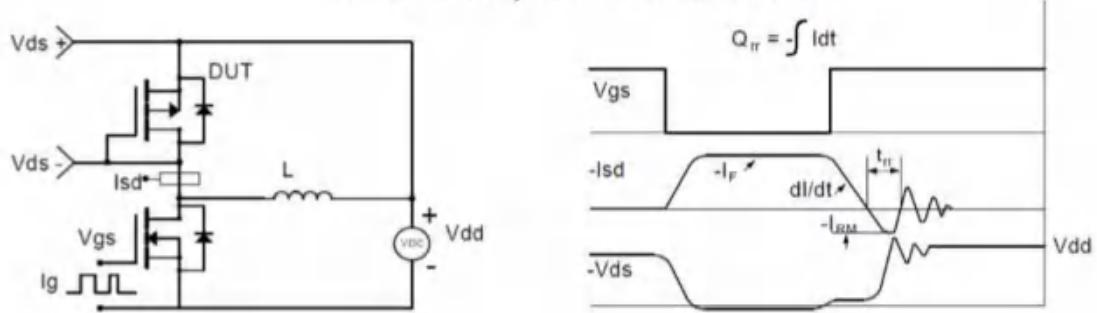
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

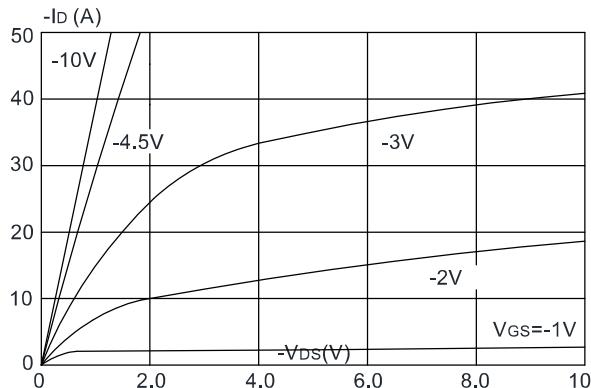


Diode Recovery Test Circuit & Waveforms

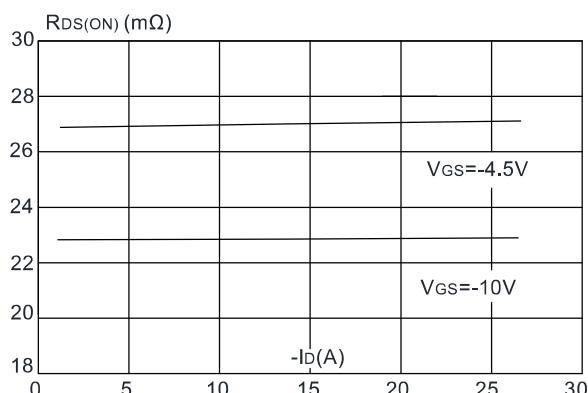


## Typical Performance Characteristics

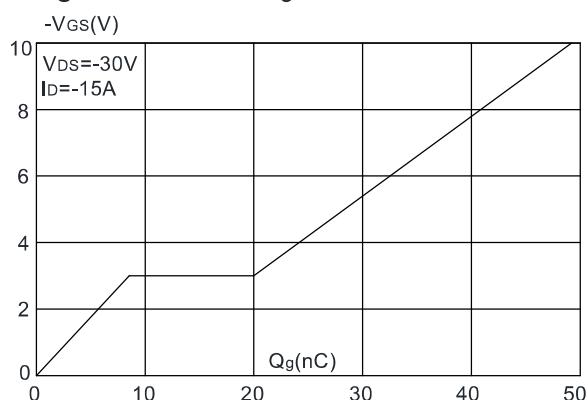
**Figure 1:** Output Characteristics



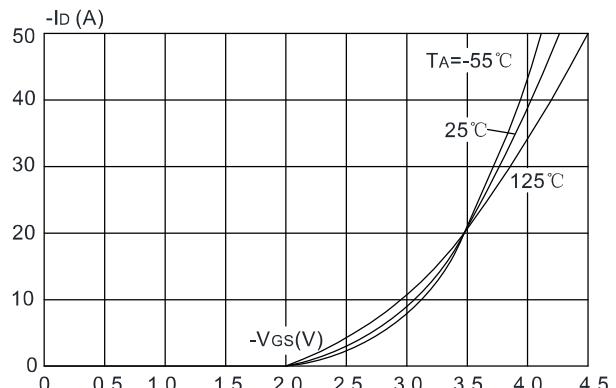
**Figure 3:** On-resistance vs. Drain Current



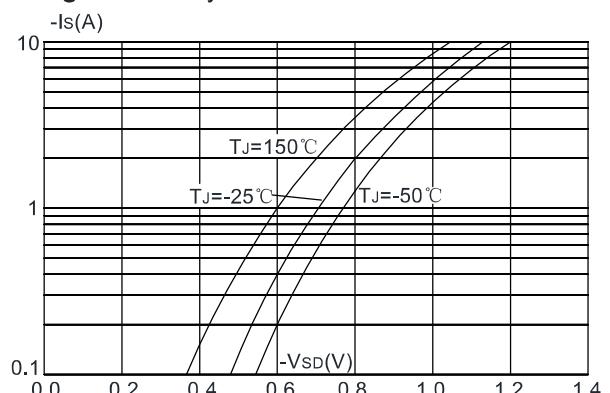
**Figure 5:** Gate Charge Characteristics



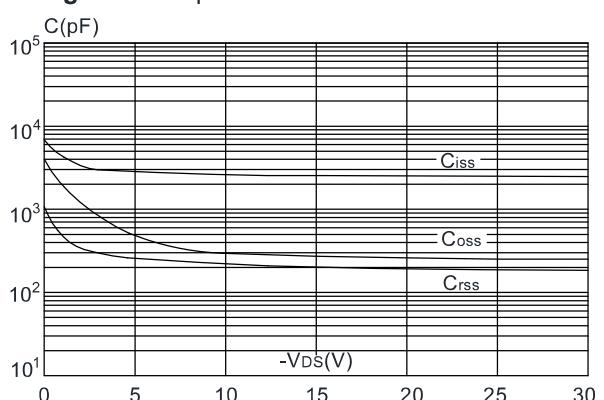
**Figure 2:** Typical Transfer Characteristics



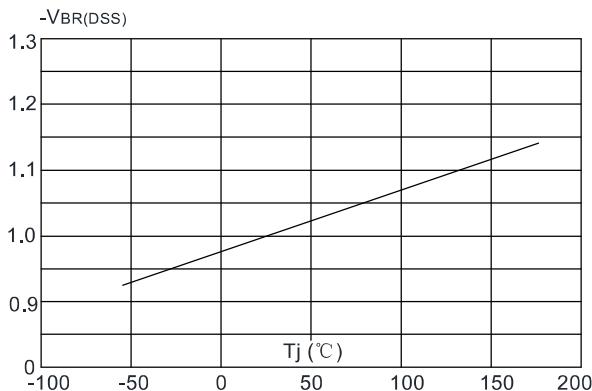
**Figure 4:** Body Diode Characteristics



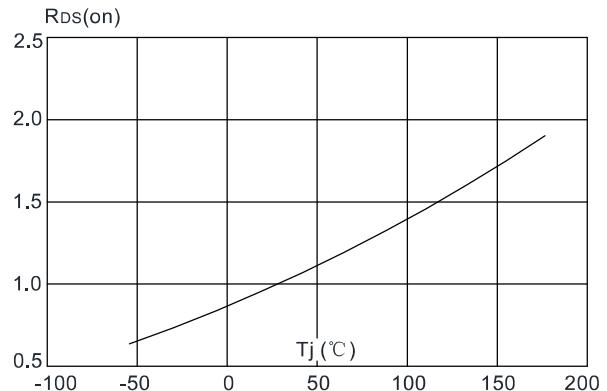
**Figure 6:** Capacitance Characteristics



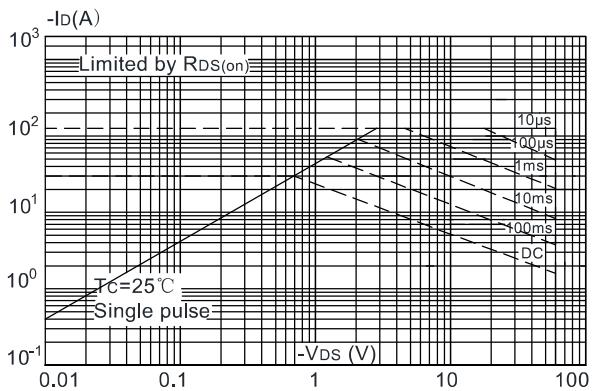
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



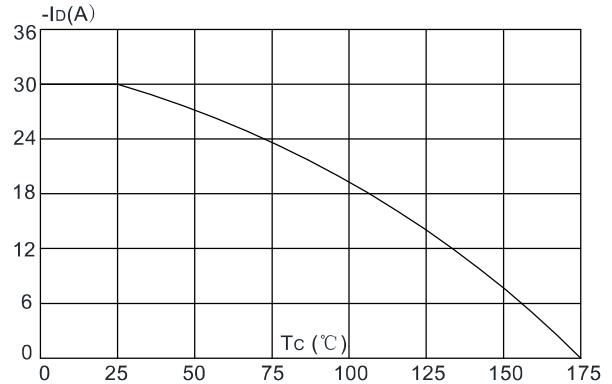
**Figure 8:** Normalized on Resistance vs. Junction Temperature



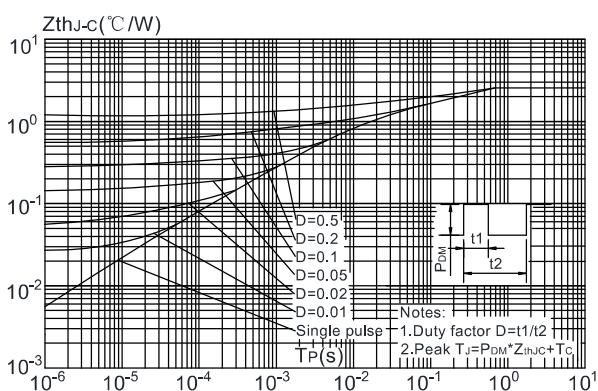
**Figure 9:** Maximum Safe Operating Area



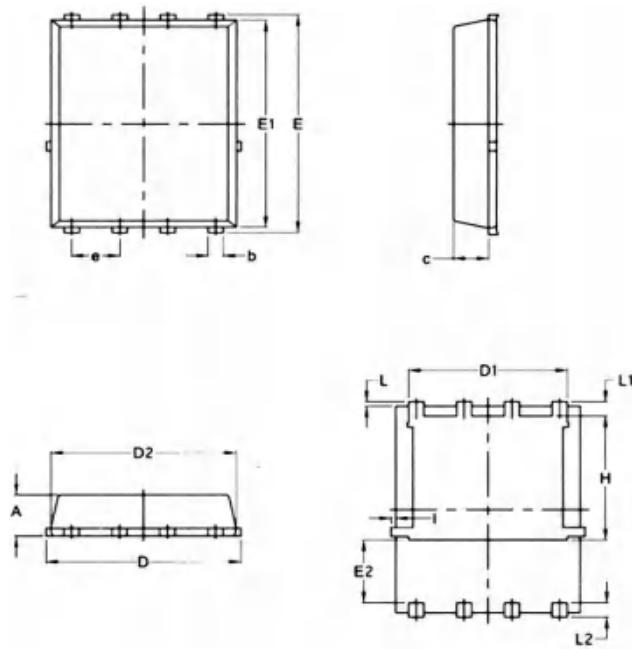
**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature



**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case



## PDFN5\*6-8L Package Information



PDFN5X6-8L

S Y M B O L	COMMON			
	MM		INCH	
	MIN.	MAX.	MIN.	MAX.
A	1.03	1.17	0.0406	0.0461
b	0.34	0.48	0.0134	0.0189
c	0.824	0.970	0.0324	0.0382
D	4.80	5.40	0.1890	0.2126
D1	4.11	4.31	0.1618	0.1697
D2	4.80	5.00	0.1890	0.1969
E	5.95	6.15	0.2343	0.2421
E1	5.65	5.85	0.2224	0.2303
E2	1.60	—	0.0630	—
e	1.27	BSC	0.05	BSC
L	0.05	0.25	0.0020	0.0098
L1	0.38	0.50	0.0150	0.0197
L2	0.38	0.50	0.0150	0.0197
H	3.30	3.50	0.1299	0.1378
I	—	0.18	—	0.0070